

FEATURES

High Speed

250 MHz -3 dB Bandwidth ($G = +1$)

3000 V/ μ s Slew Rate

21 ns Settling Time to 0.1%

1.8 ns Rise Time for 2 V Step

Low Power

3.5 mA/Amp Power Supply Current (35 mW/Amp)

Single Supply Operation

Fully Specified for +5 V Supply

Good Video Specifications ($R_L = 150 \Omega$, $G = +2$)

Gain Flatness 0.1 dB to 30 MHz

0.04% Differential Gain Error

0.10° Differential Phase Error

Low Distortion

-78 dBc THD at 5 MHz

-61 dBc THD at 20 MHz

High Output Current of 50 mA

Available in a 14-Pin PDIP and SOIC

APPLICATIONS

Image Scanners

Active Filters

Video Switchers

Special Effects

PRODUCT DESCRIPTION

The AD 8004 is a quad, low power, high speed amplifier designed to operate on single or dual supplies. It utilizes a current feedback architecture and features high slew rate of 3000 V/ μ s making the AD 8004 ideal for handling large amplitude pulses. Additionally, the AD 8004 provides gain flatness of 0.1 dB to

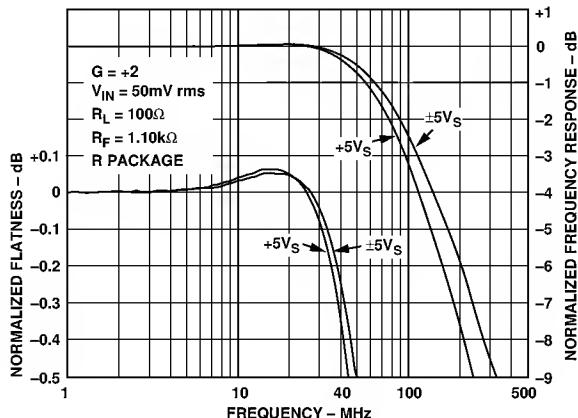


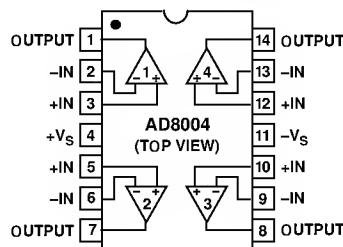
Figure 1. Frequency Response and Flatness, $G = +2$

REV. A

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CONNECTION DIAGRAM

Plastic (N) and
SOIC (R) Packages



30 MHz while offering differential gain and phase error of 0.04% and 0.10°. This makes the AD 8004 suitable for video electronics such as cameras and video switchers.

The AD 8004 offers low power of 3.5 mA/amplifier and can run on a single +4 V to +12 V power supply, while being capable of delivering up to 50 mA of load current. All this is offered in a small 14-pin DIP or 14-pin SOIC package. These features make this amplifier ideal for portable and battery powered applications where size and power are critical.

The outstanding bandwidth of 250 MHz along with 3000 V/ μ s of slew rate make the AD 8004 useful in many general purpose, high speed applications where dual power supplies of up to ± 6 V and single supplies from 4 V to 12 V are needed. The AD 8004 is available in the industrial temperature range of -40°C to +85°C.

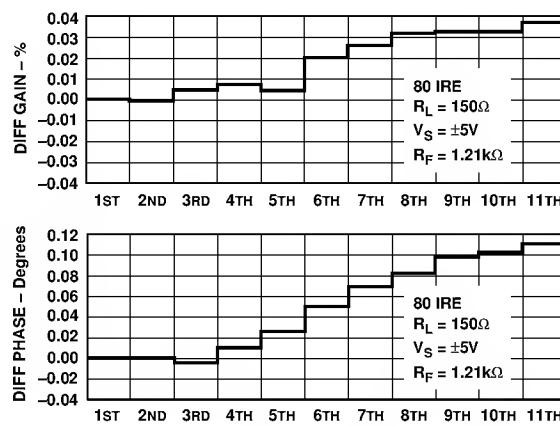


Figure 2. Differential Gain/Differential Phase

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One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106, U.S.A.
Tel: 617/329-4700 Fax: 617/326-8703

AD8004- SPECIFICATIONS

(@ $T_A = +25^\circ\text{C}$, $V_S = \pm 5 \text{ V}$, $R_L = 100 \Omega$, unless otherwise noted)

Parameter	Conditions	AD8004A		
		Min	Typ	Max
				Units
DYNAMIC PERFORMANCE				
-3 dB Bandwidth, N Package	$G = +2, R_F = 698 \Omega$ $G = +1, R_F = 806 \Omega$	185		MHz
Bandwidth for 0.1 dB Flatness	$G = +2$	250		MHz
Slew Rate	$G = +2, V_O = 4 \text{ V Step}$ $G = -2, V_O = 4 \text{ V Step}$	30		MHz
Settling Time to 0.1%	$G = +2, V_O = 2 \text{ V Step}$	3000		V/ μ s
Rise & Fall Time (10% to 90%)	$G = +2, V_O = 2 \text{ V Step}$ $G = +2, V_O = 2 \text{ V Step}$	2000		V/ μ s
		21		ns
		1.8		ns
NOISE/HARMONIC PERFORMANCE				
Total Harmonic Distortion	$f_C = 5 \text{ MHz}, V_O = 2 \text{ V p-p}, R_L = 1 \text{ k}\Omega$	-78		dBc
Crosstalk, R Package, Worst Case	$f = 5 \text{ MHz}, G = +2, R_L = 1 \text{ k}\Omega$	-69		dB
Crosstalk, N Package, Worst Case	$f = 5 \text{ MHz}, G = +2, R_L = 1 \text{ k}\Omega$	-64		dB
Input Voltage Noise	$f = 10 \text{ kHz}$	1.5		nV/ $\sqrt{\text{Hz}}$
Input Current Noise	$f = 10 \text{ kHz}, +I_n$ -In	38		pA/ $\sqrt{\text{Hz}}$
Differential Gain Error	NTSC, $G = +2, R_L = 150 \Omega, R_F = 1.21 \text{ k}\Omega$	0.04		%
Differential Phase Error	NTSC, $G = +2, R_L = 150 \Omega, R_F = 1.21 \text{ k}\Omega$	0.10		Degree
Differential Gain Error	NTSC, $G = +2, R_L = 1 \text{ k}\Omega, R_F = 1.21 \text{ k}\Omega$	0.01		%
Differential Phase Error	NTSC, $G = +2, R_L = 1 \text{ k}\Omega, R_F = 1.21 \text{ k}\Omega$	0.04		Degree
DC PERFORMANCE				
Input Offset Voltage		1.0	3.5	mV
Offset Drift	$T_{MIN}-T_{MAX}$	1.5	5	mV
-Input Bias Current		15		$\mu\text{V}/^\circ\text{C}$
+Input Bias Current	$T_{MIN}-T_{MAX}$	35	90	$\pm\mu\text{A}$
Open-Loop Transresistance	$T_{MIN}-T_{MAX}$ $V_O = \pm 2.5 \text{ V}$ $T_{MIN}-T_{MAX}$	40	110	$\pm\mu\text{A}$
		170	290	$\pm\mu\text{A}$
			220	k Ω
				k Ω
INPUT CHARACTERISTICS				
Input Resistance	+Input -Input	2		M Ω
Input Capacitance	+Input	50		Ω
Input Common-Mode Voltage Range	-Input	1.5		pF
Common-Mode Rejection Ratio	+Input	3.2		$\pm\text{V}$
Offset Voltage	$V_{CM} = \pm 2.5 \text{ V}$	52	58	dB
-Input Current	$V_{CM} = \pm 2.5 \text{ V}, T_{MIN}-T_{MAX}$	1		$\mu\text{A}/\text{V}$
+Input Current	$V_{CM} = \pm 2.5 \text{ V}, T_{MIN}-T_{MAX}$	12		$\mu\text{A}/\text{V}$
OUTPUT CHARACTERISTICS				
Output Voltage Swing	$R_L = 150 \Omega$	3.9		$\pm\text{V}$
Output Current		50		mA
Short Circuit Current		100	180	mA
POWER SUPPLY				
Operating Range		± 2.0	± 6.0	V
Total Quiescent Current		14	17	mA
Power Supply Rejection Ratio	$T_{MIN}-T_{MAX}$ $\Delta V_S = \pm 2 \text{ V}$	16	20	mA
-Input Current	$T_{MIN}-T_{MAX}$	56	62	dB
+Input Current	$T_{MIN}-T_{MAX}$	0.5		$\mu\text{A}/\text{V}$
		4		$\mu\text{A}/\text{V}$

Specifications subject to change without notice.

(@ $T_A = +25^\circ\text{C}$, $V_S = +5\text{ V}$, $R_L = 100\ \Omega$, unless otherwise noted)

AD8004

Parameter	Conditions	Min	AD8004A Typ	Max	Units
DYNAMIC PERFORMANCE					
-3 dB Bandwidth, N Package	$G = +2$, $R_F = 698\ \Omega$ $G = +1$, $R_F = 806\ \Omega$	150			MHz
Bandwidth for 0.1 dB Flatness	$G = +2$	200			MHz
Slew Rate	$G = +2$, $V_O = 2\text{ V Step}$	30			MHz
Settling Time to 0.1%	$G = +2$, $V_O = 2\text{ V Step}$	1100			V/ μs
Rise & Fall Time (10% to 90%)	$G = +2$, $V_O = 2\text{ V Step}$	24			ns
	$G = +2$, $V_O = 2\text{ V Step}$	2.3			ns
NOISE/HARMONIC PERFORMANCE					
Total Harmonic Distortion	$f_C = 5\text{ MHz}$, $V_O = 2\text{ V p-p}$, $R_L = 1\text{ k}\Omega$	-65			dBc
Crosstalk, R Package, Worst Case	$f = 5\text{ MHz}$, $G = +2$, $R_L = 1\text{ k}\Omega$	-69			dB
Crosstalk, N Package, Worst Case	$f = 5\text{ MHz}$, $G = +2$, $R_L = 1\text{ k}\Omega$	-64			dB
Input Voltage Noise	$f = 10\text{ kHz}$	1.5			nV/ $\sqrt{\text{Hz}}$
Input Current Noise	$f = 10\text{ kHz}$, $+I_{in}$ - I_{in}	38			pA/ $\sqrt{\text{Hz}}$
Differential Gain Error	NTSC, $G = +2$, $R_L = 150\ \Omega$, $R_F = 1.21\text{ k}\Omega$	0.06			%
Differential Phase Error	NTSC, $G = +2$, $R_L = 150\ \Omega$, $R_F = 1.21\text{ k}\Omega$	0.25			Degree
Differential Gain Error	NTSC, $G = +2$, $R_L = 1\text{ k}\Omega$, $R_F = 1.21\text{ k}\Omega$	0.01			%
Differential Phase Error	NTSC, $G = +2$, $R_L = 1\text{ k}\Omega$, $R_F = 1.21\text{ k}\Omega$	0.08			Degree
DC PERFORMANCE					
Input Offset Voltage	$T_{MIN}-T_{MAX}$	1.0	2.5		mV
Offset Drift	$T_{MIN}-T_{MAX}$	1	3		mV
-Input Bias Current	$T_{MIN}-T_{MAX}$	15			$\mu\text{V}/^\circ\text{C}$
+Input Bias Current	$T_{MIN}-T_{MAX}$	20	80		$\pm\mu\text{A}$
Open Loop Transresistance	$T_{MIN}-T_{MAX}$ $V_O = +1.5\text{ V to }+3.5\text{ V}$ $T_{MIN}-T_{MAX}$	35	100		$\pm\mu\text{A}$
		140	230	115	$\pm\mu\text{A}$
			170		k Ω
					k Ω
INPUT CHARACTERISTICS					
Input Resistance	+Input	2			M Ω
	-Input	50			Ω
	+Input	1.5			pF
Input Capacitance		3.2			V
Input Common-Mode Voltage Range					
Common-Mode Rejection Ratio					
Offset Voltage	$V_{CM} = +1\text{ V to }+3\text{ V}$	52	57		dB
-Input Current	$V_{CM} = +1\text{ V to }+3\text{ V}$, $T_{MIN}-T_{MAX}$		2		$\mu\text{A/V}$
+Input Current	$V_{CM} = +1\text{ V to }+3\text{ V}$, $T_{MIN}-T_{MAX}$		15		$\mu\text{A/V}$
OUTPUT CHARACTERISTICS					
Output Voltage Swing	$R_L = 150\ \Omega$		0.9 to 4.1		V
Output Current			50		mA
Short Circuit Current			95		mA
POWER SUPPLY					
Operating Range		0, +4	+12		V
Total Quiescent Current			13	14	mA
			14.5	15.5	mA
Power Supply Rejection Ratio	$\Delta V_S = +1\text{ V}$, $V_{CM} = +2.5\text{ V}$	56	62		dB
-Input Current	$T_{MIN}-T_{MAX}$		1		$\mu\text{A/V}$
+Input Current	$T_{MIN}-T_{MAX}$		6		$\mu\text{A/V}$

Specifications subject to change without notice.

AD8004

ABSOLUTE MAXIMUM RATINGS¹

Supply Voltage	12.6 V
Internal Power Dissipation ²	
Plastic Package (N)	Observe Derating Curves
Small Outline Package (R)	Observe Derating Curves
Input Voltage (Common Mode)	$\pm V_S$
Differential Input Voltage	± 2.5 V
Output Short Circuit Duration	Observe Power Derating Curves
Storage Temperature Range (N, R)	-65°C to +125°C
Operating Temperature Range (A Grade)	-40°C to +85°C
Lead Temperature Range (Soldering 10 sec)	+300°C

NOTES

¹Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

²Specification is for device in free air:

14-Pin Plastic Package: $\theta_{JA} = 90^\circ\text{C}/\text{Watt}$
14-Pin SOIC Package: $\theta_{JA} = 140^\circ\text{C}/\text{Watt}$

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option
AD8004AN	-40°C to +85°C	14-Pin Plastic DIP	N-14
AD8004AR-14	-40°C to +85°C	14-Pin SOIC	R-14
AD8004AR-14-REEL	-40°C to +85°C	14-Pin SOIC	R-14
AD8004AR-14-REEL7	-40°C to +85°C	14-Pin SOIC	R-14

MAXIMUM POWER DISSIPATION

The maximum power that can be safely dissipated by the AD 8004 is limited by the associated rise in junction temperature. The maximum safe junction temperature for plastic encapsulated devices is determined by the glass transition temperature of the plastic, approximately +150°C. Exceeding this limit temporarily may cause a shift in parametric performance due to a change in the stresses exerted on the die by the package. Exceeding a junction temperature of +175°C for an extended period can result in device failure.

While the AD 8004 is internally short circuit protected, this may not be sufficient to guarantee that the maximum junction temperature is not exceeded under all conditions. To ensure proper operation, it is necessary to observe the maximum power derating curves (shown below in Figure 3).

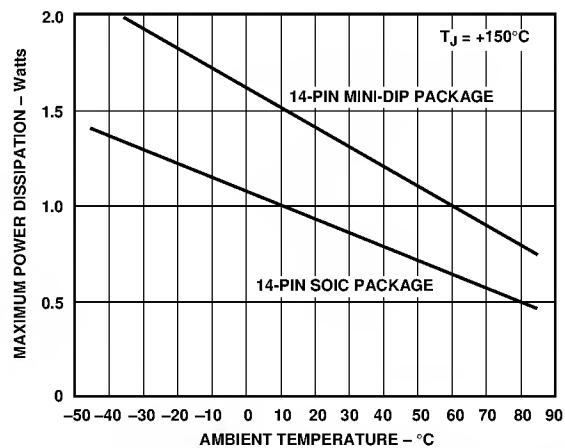


Figure 3. Maximum Power Dissipation vs. Temperature

CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the AD 8004 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



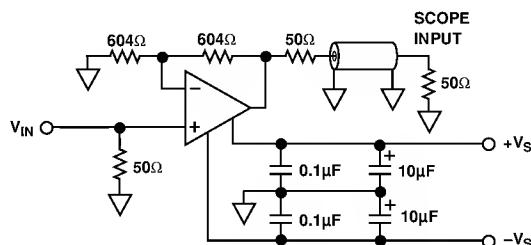


Figure 4. Test Circuit; Gain = +2

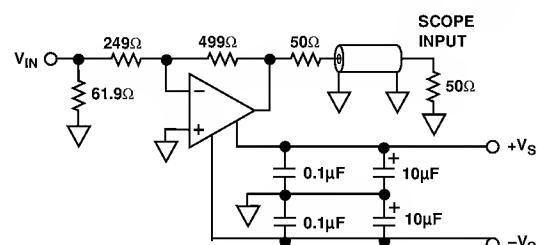
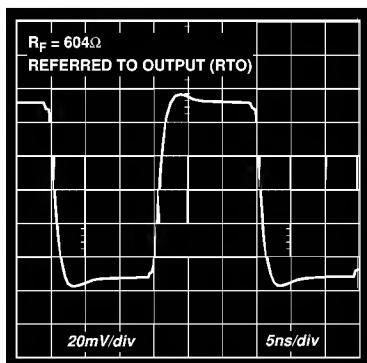
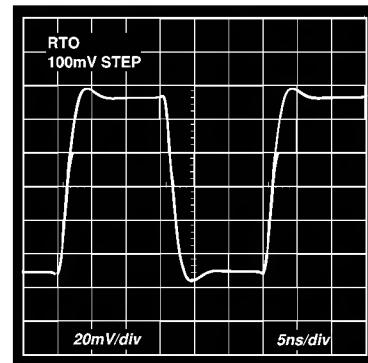
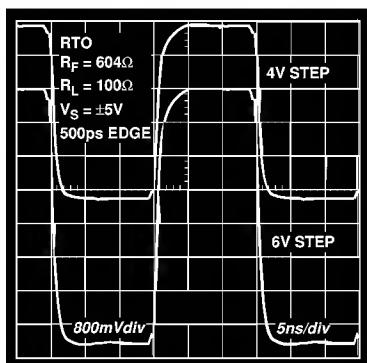
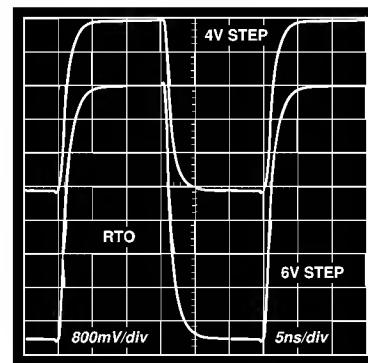
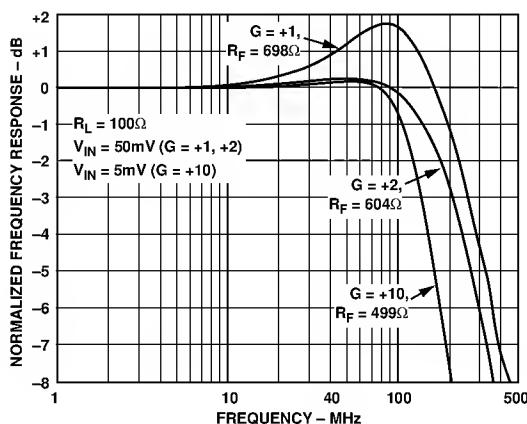
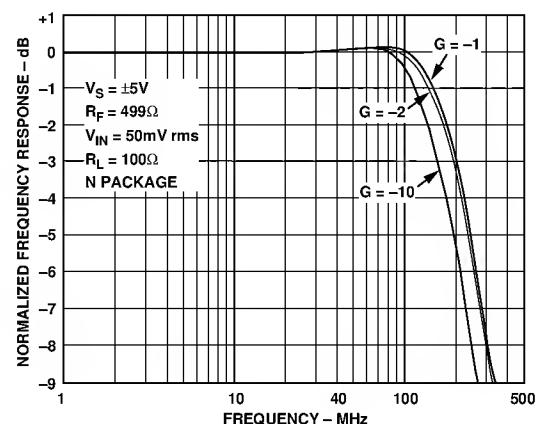


Figure 8. Test Circuit; Gain = -2

Figure 5.* 100 mV Step Response; $G = +2$, $V_S = \pm 2.5\text{ V}$ or $\pm 5\text{ V}$ Figure 9.* 100 mV Step Response; $G = -2$, $V_S = \pm 2.5\text{ V}$ or $\pm 5\text{ V}$ Figure 6.* Step Response; $G = +2$, $V_S = \pm 5\text{ V}$ Figure 10.* Step Response; $G = -2$, $V_S = \pm 5\text{ V}$ Figure 7. Frequency Response; $G = +1, +2, +10$, $V_S = \pm 5\text{ V}$

*NOTE: $V_S = \pm 2.5\text{ V}$ operation is identical to $V_S = +5\text{ V}$ single supply operation.

Figure 11. Frequency Response, $G = -1, -2, -10$

AD8004

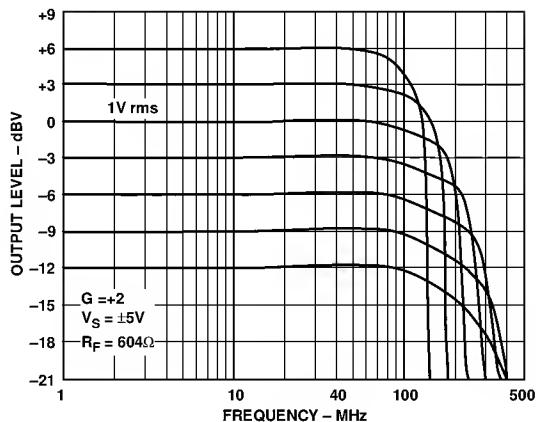


Figure 12. Large Signal Frequency Response; $V_S = \pm 5.0 V$, $G = +2$, $R_F = 604 \Omega$

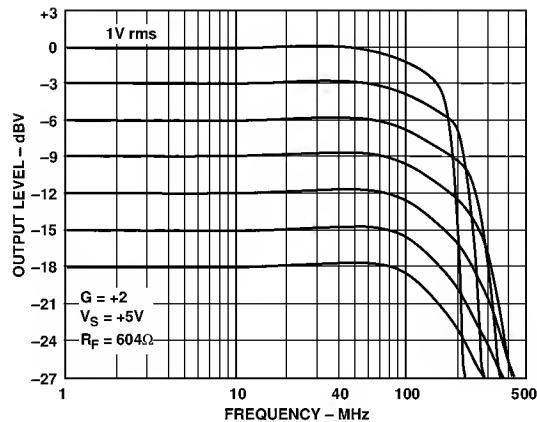


Figure 15. Large Signal Frequency Response; $V_S = +5.0 V$, $G = +2$, $R_F = 604 \Omega$

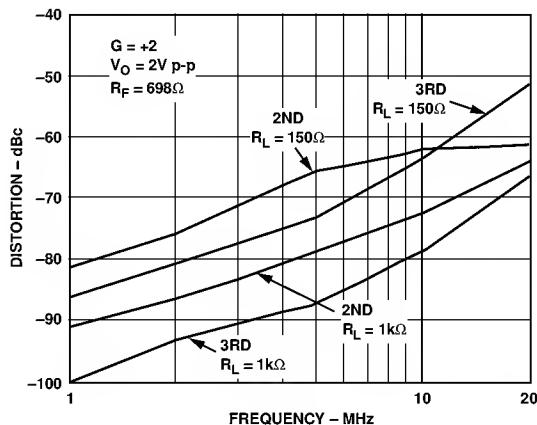


Figure 13. Distortion vs. Frequency; $V_S = \pm 5 V$

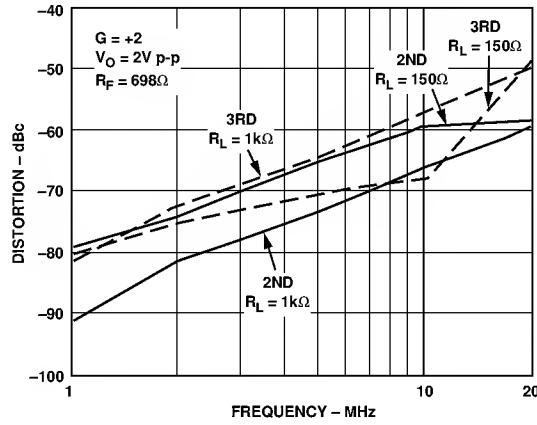


Figure 16. Distortion vs. Frequency; $V_S = +5 V$

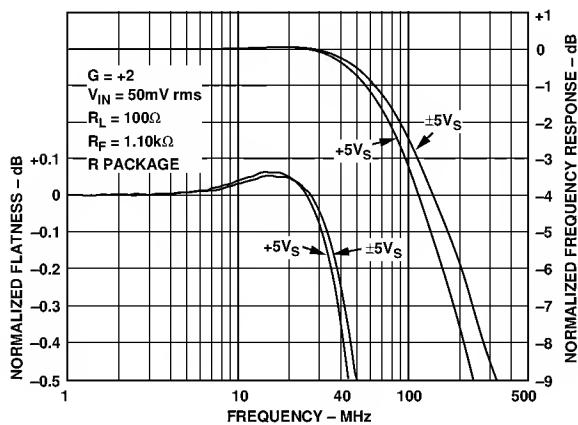


Figure 14. Frequency Response and Flatness, $G = +2$

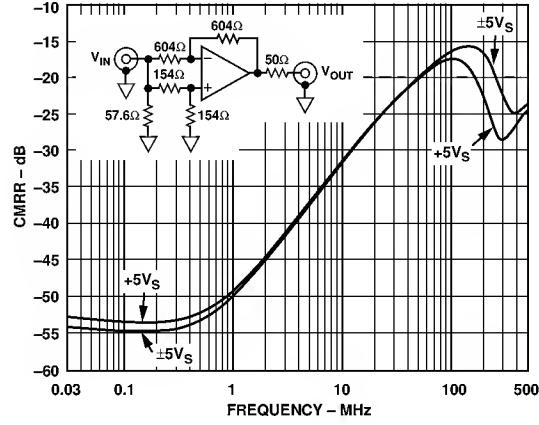


Figure 17. CMRR vs. Frequency; $V_S = \pm 5 V$ or $+5 V$, $V_{IN} = 200 mV rms$, Other Sides Are Equal, RTO

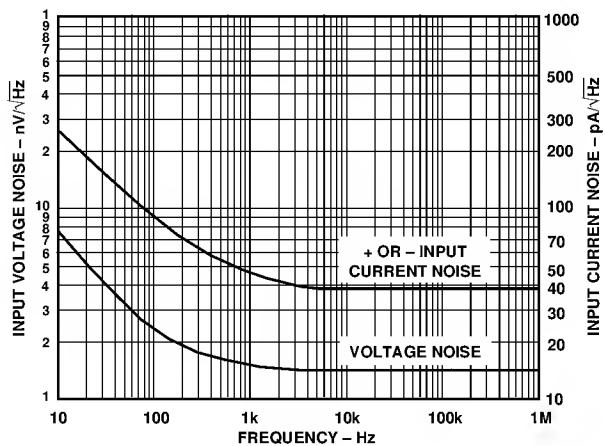
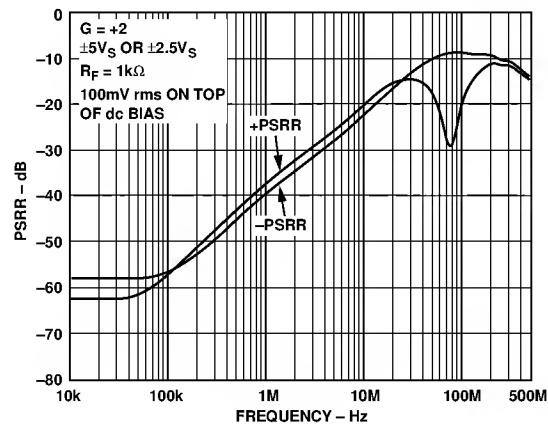
Figure 18. Noise vs. Frequency, $V_S = +5\text{ V}$ or $\pm 5\text{ V}_S$ 

Figure 21. PSRR vs. Frequency

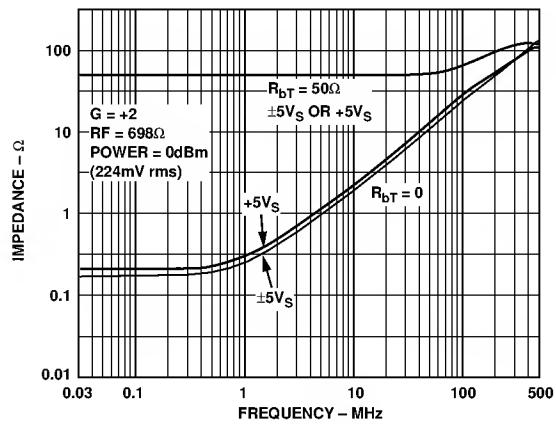


Figure 19. Output Impedance vs. Frequency

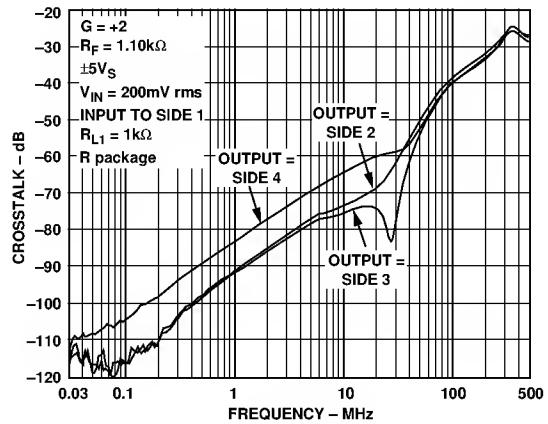


Figure 22. Crosstalk (Output to Output) vs. Frequency

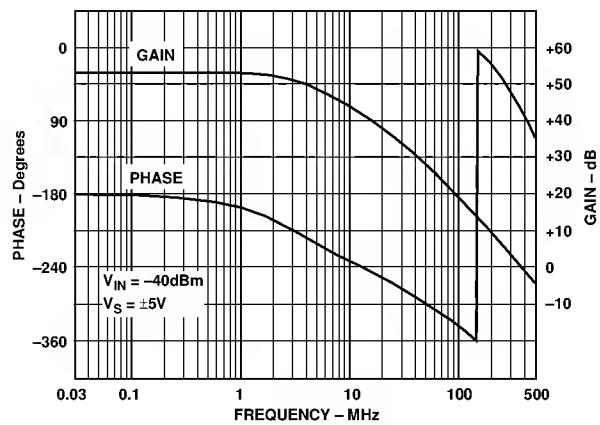


Figure 20. Open-Loop Voltage Gain and Phase

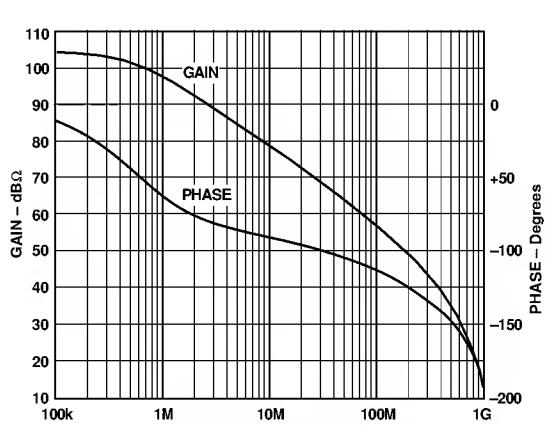


Figure 23. Open-Loop Transimpedance Gain

AD8004

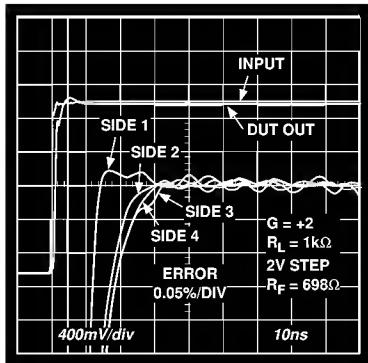


Figure 24. Short-Term Settling Time

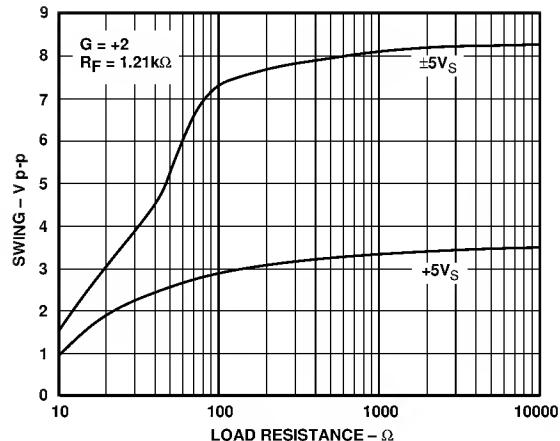


Figure 27. Output Voltage Swing vs. Load

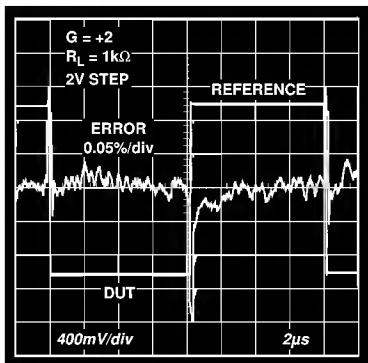


Figure 25. Long-Term Settling Time

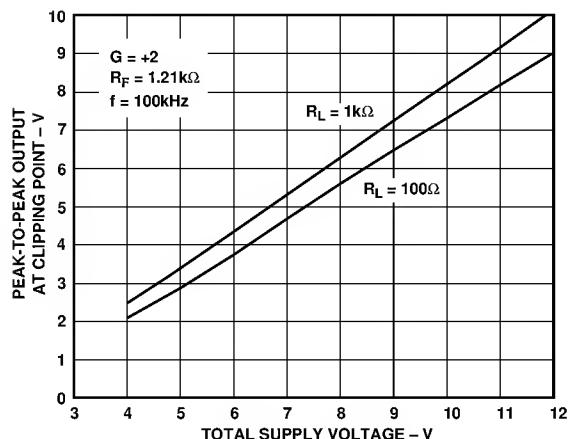


Figure 28. Output Swing vs. Supply

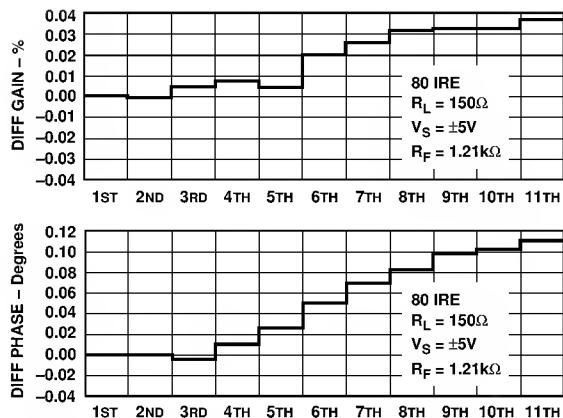


Figure 26. Differential Gain/Differential Phase

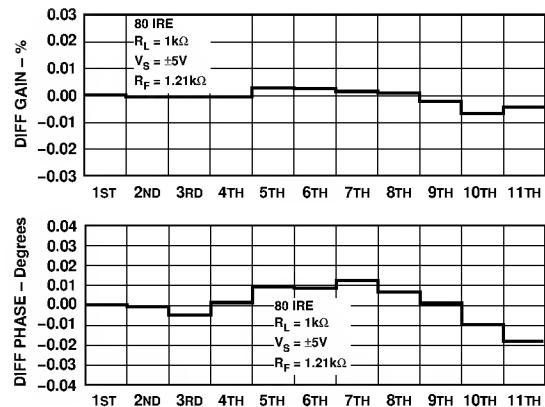


Figure 29. Differential Gain/Phase, $R_L = 1\text{k}\Omega$

THEORY OF OPERATION

The AD 8004 is a member of a new family of high speed current-feedback (CF) amplifiers offering new levels of bandwidth, distortion, and signal-swing capability vs. power. Its wide dynamic range capabilities are due to both a complementary high speed bipolar process and a new design architecture. The AD 8004 is basically a two stage (Figure 30) rather than the conventional one stage design. Both stages feature the current-on-demand property associated with current feedback amplifiers. This gives an unprecedented ratio of quiescent current to dynamic performance. The important properties of slew rate, and full power bandwidth benefit from this performance. In addition the second gain stage buffers the effects of load impedance significantly reducing distortion.

A full discussion of this new amplifier architecture is available on the data sheet for the AD 8011. This discussion only covers the basic principles of operation.

DC AND AC CHARACTERISTICS

As with traditional op amp circuits the dc closed-loop gain is defined as:

$$A_V = G = 1 + \frac{R_F}{R_N} \quad \text{noninverting operation}$$

$$A_V = G = -\frac{R_F}{R_N} \quad \text{inverting operation}$$

The more exact relationships that take into account open-loop gain errors are:

$$A_V = \frac{G}{1 + \frac{1-G}{A_0(s)} + \frac{R_F}{T_0(s)}} \quad \text{for inverting (G is negative)}$$

$$A_V = \frac{G}{1 + \frac{G}{A_0(s)} + \frac{R_F}{T_0(s)}} \quad \text{for noninverting (G is positive)}$$

In these equations the open-loop voltage gain ($A_0(s)$) is common to both voltage and current-feedback amplifiers and is the ratio of output voltage to differential input voltage. The open-loop transimpedance gain ($T_0(s)$) is the ratio of output voltage to inverting input current and is applicable to current-feedback amplifiers. The open-loop voltage gain and open-loop transimpedance gain ($T_0(s)$) of the AD 8004 are plotted vs. frequency in Figures 20 and 31. These plots and the basic relationships can be used to predict the first order performance of the AD 8004 over frequency. At low closed-loop gains the term ($R_F/T_0(s)$) dominates the frequency response characteristics. This gives the result that bandwidth is constant with gain, a familiar property of current feedback amplifiers.

An R_F of 1 kΩ has been chosen as the nominal value to give optimum frequency response with acceptable peaking at gains of +2/-1. As can be seen from the above relationships, at higher closed-loop gains reducing R_F has the effect of increasing closed-loop bandwidth. Table I gives optimum values for R_F and R_G for a variety of gains.

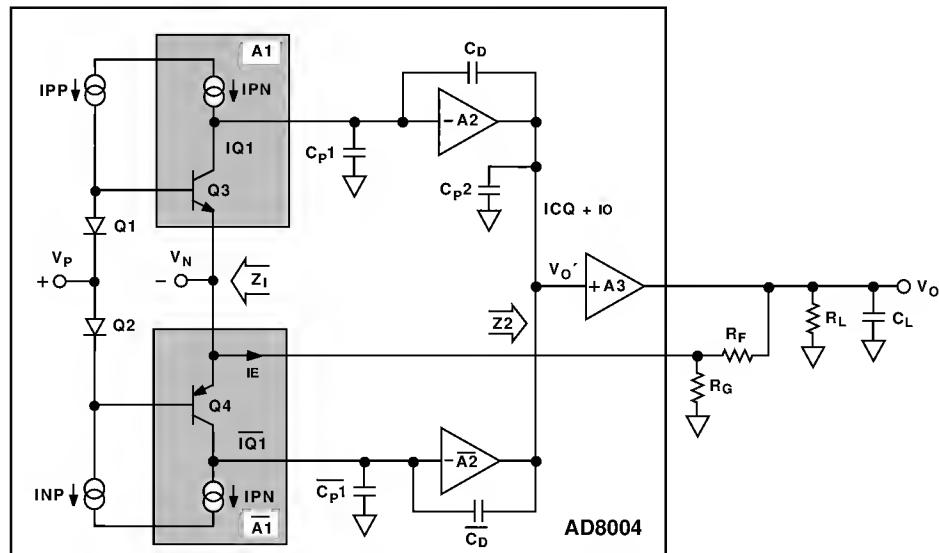


Figure 30. Simplified Block Diagram

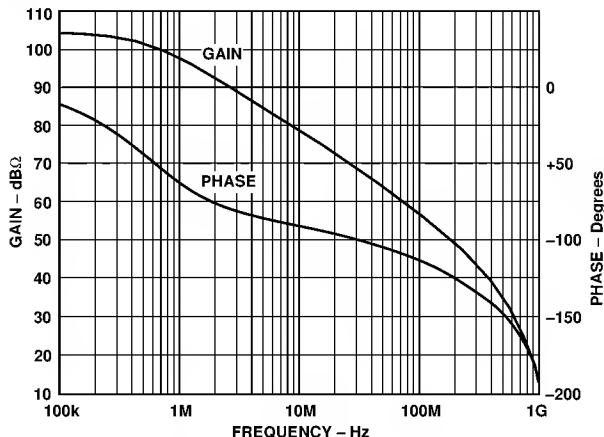


Figure 31. Open-Loop Transimpedance Gain

DRIVING CAPACITIVE LOADS

The AD8004 was designed primarily to drive nonreactive loads. If driving loads with a capacitive component is desired, best settling response is obtained by the addition of a small series resistance as shown in Figure 32. The accompanying graph shows the optimum value for R_{SERIES} vs. capacitive load. It is worth noting that the frequency response of the circuit when driving large capacitive loads will be dominated by the passive roll-off of R_{SERIES} and C_L .

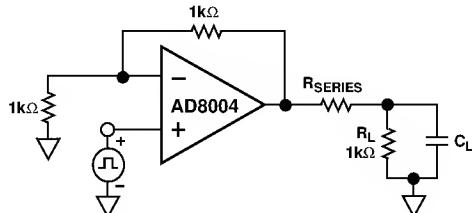
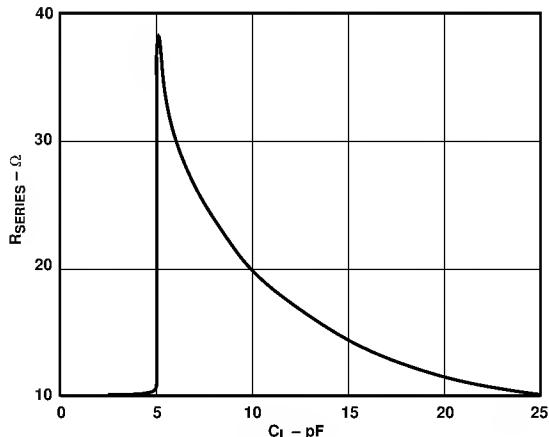


Figure 32. Driving Capacitive Load

Figure 33. Recommended R_{SERIES} vs. Capacitive Load for ≤ 30 ns Settling to 0.1%**OPTIMIZING FLATNESS**

The fine scale gain flatness and -3 dB bandwidth is affected by $R_{FEEDBACK}$ selection as is normal of current feedback amplifiers. With exception of gain = +1, the AD8004 can be adjusted for either maximal flatness with modest closed-loop bandwidth or for mildly peaked-up frequency response with much more bandwidth. Figure 34 shows the effect of three evenly spaced R_F changes upon gain = +1 and gain = +2. Table I shows the recommended component values for achieving maximally flat fre-

quency response as well as a faster slightly peaked-up frequency response.

Printed circuit board parasitics and device lead frame parasitics also control fine scale gain flatness. The AD8004R package because of its small lead frame offers superior parasitics relative to the N package. In the printed circuit board environment, parasitics such as extra capacitance caused by two parallel and vertical flat conductors on opposite PC board sides in the region of the summing junction will cause some bandwidth extension and/or increased peaking. In noninverting gains, the effect of extra capacitance on summing junctions is far more pronounced than versus inverting gains. Figure 35 shows an example of this. Note that only 1 pF of added junction capacitance causes about a 70% bandwidth extension and additional peaking on a gain = +2. For an inverting gain = -2, 5 pF of additional summing junction capacitance caused a small 10% bandwidth extension.

Extra output capacitive loading also causes bandwidth extensions and peaking. The effect is more pronounced with less resistive loading from the next stage. Figure 36 shows the effect of direct output capacitive loads for gains of +2 and -2. For both gains C_{LOAD} was set to 10 pF or 0 pF (no extra capacitive loading). For each of the four traces in Figure 36 the resistive loads were 100 Ω. Figure 37 also shows capacitive loading effects only with a lighter output resistive load. Note that even though bandwidth is extended 2×, the flatness dramatically suffers.

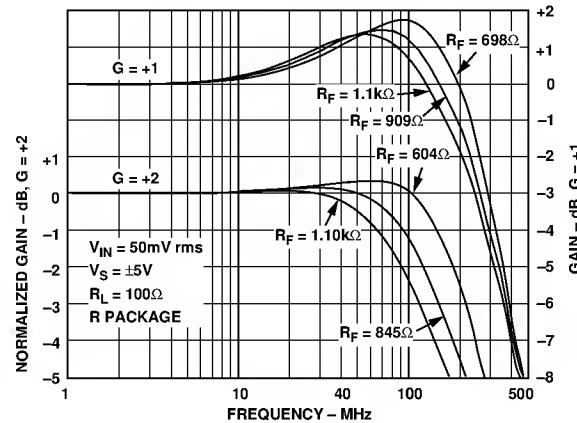
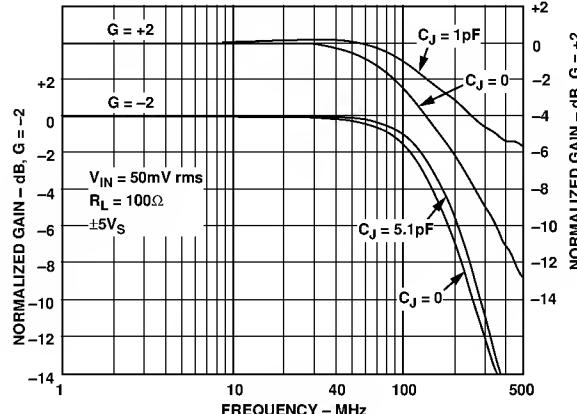
Figure 34. $R_{FEEDBACK}$ vs. Frequency Response, $G = +1/+2$ 

Figure 35. Frequency Response vs. Added Summing Junction Capacitance

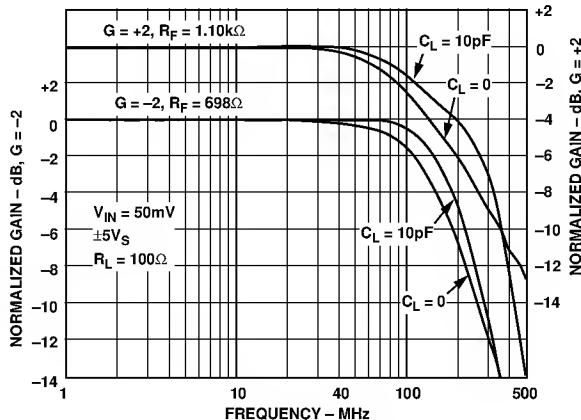


Figure 36. Frequency Response vs. Capacitive Loading,
 $R_L = 100 \Omega$ Output

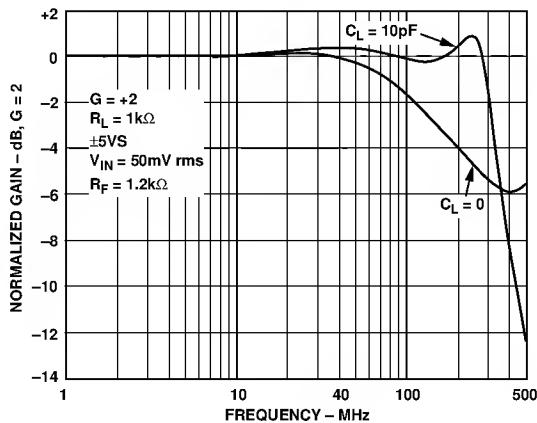


Figure 37. Flatness with 10 pF Capacitive Load

DRIVING A SINGLE-SUPPLY A/D CONVERTER

New CMOS A/D converters are placing greater demands on the amplifiers that drive them. Higher resolutions, faster conversion rates and input switching irregularities require superior settling characteristics. In addition, these devices run off a single +5 V supply and consume little power, so good single-supply operation with low power consumption are very important. The AD 8004 is well positioned for driving this new class of A/D converters.

Figure 38 shows a circuit that uses an AD 8004 to drive an AD 876, a single supply, 10-bit, 20 M SPS A/D converter that requires only 140 mW. Using the AD 8004 for level shifting and driving, the A/D exhibits no degradation in performance compared to when it is driven from a signal generator.

The analog input of the AD 876 spans 2 V centered at about 2.6 V. The resistor network and bias voltages provide the level shifting and gain required to convert the 0 V to 1 V input signal to a 3.6 V to 1.6 V range that the AD 876 wants to see.

Biasing the noninverting input of the AD 8004 at 1.6 V dc forces the inverting input to be at 1.6 V dc for linear operation of the amplifier. When the input is at 0 V, there is 3.2 mA flowing out of the summing junction via R1 ($1.6\text{ V}/499\text{ }\Omega$). R3 has a current of 1.2 mA flowing into the summing junction ($3.6\text{ V}-1.6\text{ V})/1.65\text{ k}\Omega$). The difference of these two currents (2 mA) must flow

through R2. This current flows toward the summing junction and requires that the output be 2 V higher than the summing junction or at 3.6 V.

When the input is at 1 V, there is 1.2 mA flowing into the summing junction through R3 and 1.2 mA flowing out through R1. These currents balance and leave no current to flow through R2. Thus the output is at the same potential as the inverting input or 1.6 V.

The input of the AD876 has a series MOSFET switch that turns on and off at the sampling rate. This MOSFET is connected to a hold capacitor internal to the device. The on impedance of the MOSFET is about $50\ \Omega$, while the hold capacitor is about 5 pF .

In a worst case condition, the input voltage to the AD876 will change by a full-scale value (2 V) in one sampling cycle. When the input MOSFET turns on, the output of the op amp will be connected to the charged hold capacitor through the series resistance of the MOSFET. Without any other series resistance, the instantaneous current that flows would be 40 mA. This would cause settling problems for the op amp.

The series $100\ \Omega$ resistor limits the current that flows instantaneously after the MOSFET turns on to about 13 mA. This resistor cannot be made too large or the high frequency performance will be affected.

The sampling MOSFET of the AD 876 is closed for only half of each cycle or for 25 ns. Approximately 7 time constants are required for settling to 10 bits. The series 100 Ω resistor along with the 50 Ω on resistance and the hold capacitor, create a 750 ps time constant. These values leave a comfortable margin for settling. Obtaining the same results with the op amp A/D combination as compared to driving with a signal generator indicates that the op amp is settling fast enough.

Overall the AD 8004 provides adequate buffering for the AD 876 A/D converter without introducing distortion greater than that of the A/D converter by itself.

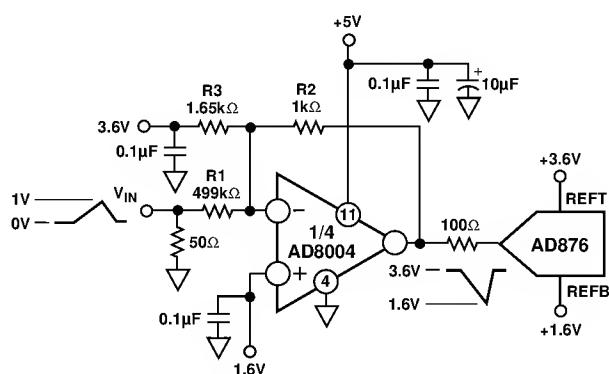


Figure 38. AD8004 Driving the AD876

LAYOUT CONSIDERATIONS

The specified high speed performance of the AD 8004 requires careful attention to board layout and component selection. Table I shows the recommended component values for the AD 8004 and Figures 40-42 show the layout for the AD 8004 evaluation boards (14-pin DIP and SOIC). Proper R_F design techniques and low parasitic component selection are mandatory.

AD8004

The PCB should have a ground plane covering all unused portions of the component side of the board to provide a low impedance ground path. The ground plane should be removed from the area near the input pins to reduce stray capacitance.

Chip capacitors should be used for supply bypassing (see Figure 39). One end should be connected to the ground plane and the other within 1/8 in. of each power pin. An additional (4.7 μ F–10 μ F) tantalum electrolytic capacitor should be connected in parallel.

The feedback resistor should be located close to the inverting input pin in order to keep the stray capacitance at this node to a minimum. Capacitance greater than 1 pF at the inverting input will significantly affect high speed performance when operating at low noninverting gains. An example of extra inverting input capacitance can be seen on Figure 36 plot.

Stripline design techniques should be used for long signal traces (greater than about 1 in.). These should be designed with the proper system characteristic impedance and be properly terminated at each end.

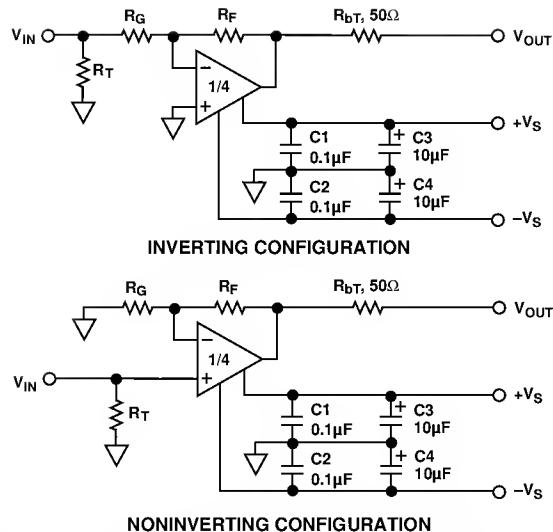


Figure 39. Inverting and Noninverting Configurations

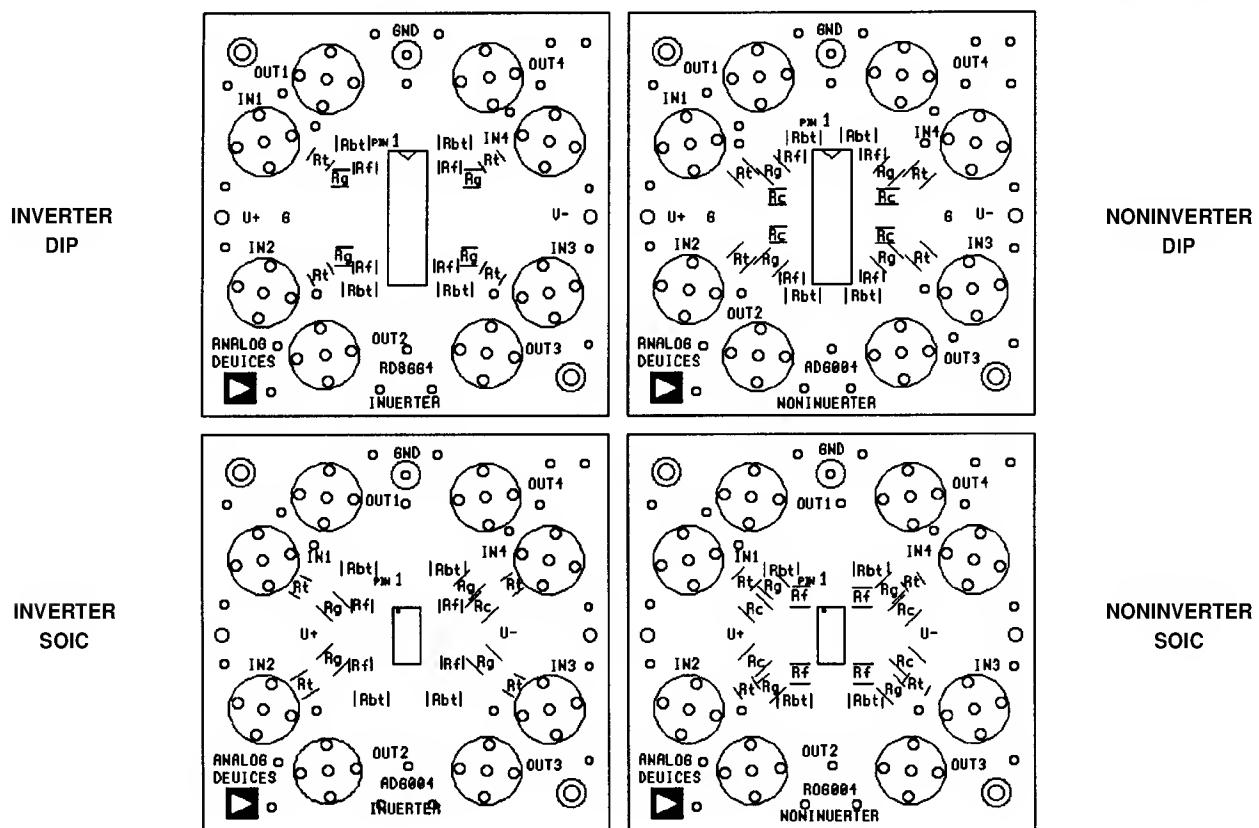
Table I. Recommended Component Values and Typical Bandwidths

Gain	-10	-2	Alternate -2	-1	Alternate -1	+1	Alternate +1	+2	Alternate +2	+10
AD8004AN (DIP) PACKAGE TYPE										
R _F (Ω)	499	698	499	649	499	1.21 k	806	1.10 k	698	499
R _G (Ω)	49.9	348	249	649	499	-	-	1.10 k	698	54.9
R _T (Ω)	None	57.6	61.9	53.6	54.9	50	50	50	50	50
Small Signal BW @ $\pm 5 V_S$ (MHz)	155	125	180	135	190	150	250	115	185	135
Peaking @ $\pm 5 V_S$	< 0.3 dB	None	0.3 dB	None	0.3 dB	1.3 dB	1.7 dB	< 0.14 dB	0.4 dB	< 0.3 dB
0.1 dB Flatness @ $\pm 5 V_S$ (MHz)	-	25	-	30	-	-	-	35	-	-
Small Signal BW @ $+5 V_S$ (MHz)	135	105	155	120	160	130	200	95	150	120
AD8004AR (SOIC) PACKAGE TYPE										
R _F (Ω)	499	698	499	750	499	1.10 k	698	1.10 k	604	499
R _G (Ω)	49.9	348	249	750	499	-	-	1.10 k	604	54.9
R _T (Ω)	None	57.6	61.9	53.6	54.9	50	50	50	50	50
Small Signal BW @ $\pm 5 V_S$ (MHz)	155	130	190	125	195	150	225	110	175	135
Peaking @ $\pm 5 V_S$	< 0.7 dB	< 0.1 dB	0.5 dB	None	0.4 dB	1.3 dB	1.8 dB	< 0.1 dB	0.5 dB	< 0.2 dB
0.1 dB Flatness @ $\pm 5 V_S$ (MHz)	-	35	-	25	-	-	-	30	-	-
Small Signal BW @ $+5 V_S$ (MHz)	135	115	175	110	165	130	195	95	155	120

NOTES

¹R_T chosen for 50 Ω characteristic input impedance.

²Resistor values listed are standard 1% tolerance.



NOTES:

1. R_T (INPUT TERMINATION RESISTOR) IS MOUNTED ON BOARD BOTTOMS.
2. R_C (IN SERIES WITH INPUT) IS A SHORT ON AD8004.
3. BYPASS CHIP CAPACITORS ARE MOUNTED ON BOARD BOTTOM WITH $0.1\mu F$ BEING CLOSEST TO SUPPLY PINS.
4. ON BOTH INVERTER BOARDS R_G , R_F AND R_{BT} ARE MOUNTED ON BOARD TOP.
5. ON NONINVERTER DIP BOARD, R_F AND R_{BT} ARE ON BOARD TOP WHILE R_G IS ON BOTTOM. ON NONINVERTER SOIC BOARD, R_{BT} IS ON TOP WHILE R_F AND R_G ARE ON BOARD BOTTOM.

Figure 40. Evaluation Board Silkscreen (Top)

AD8004

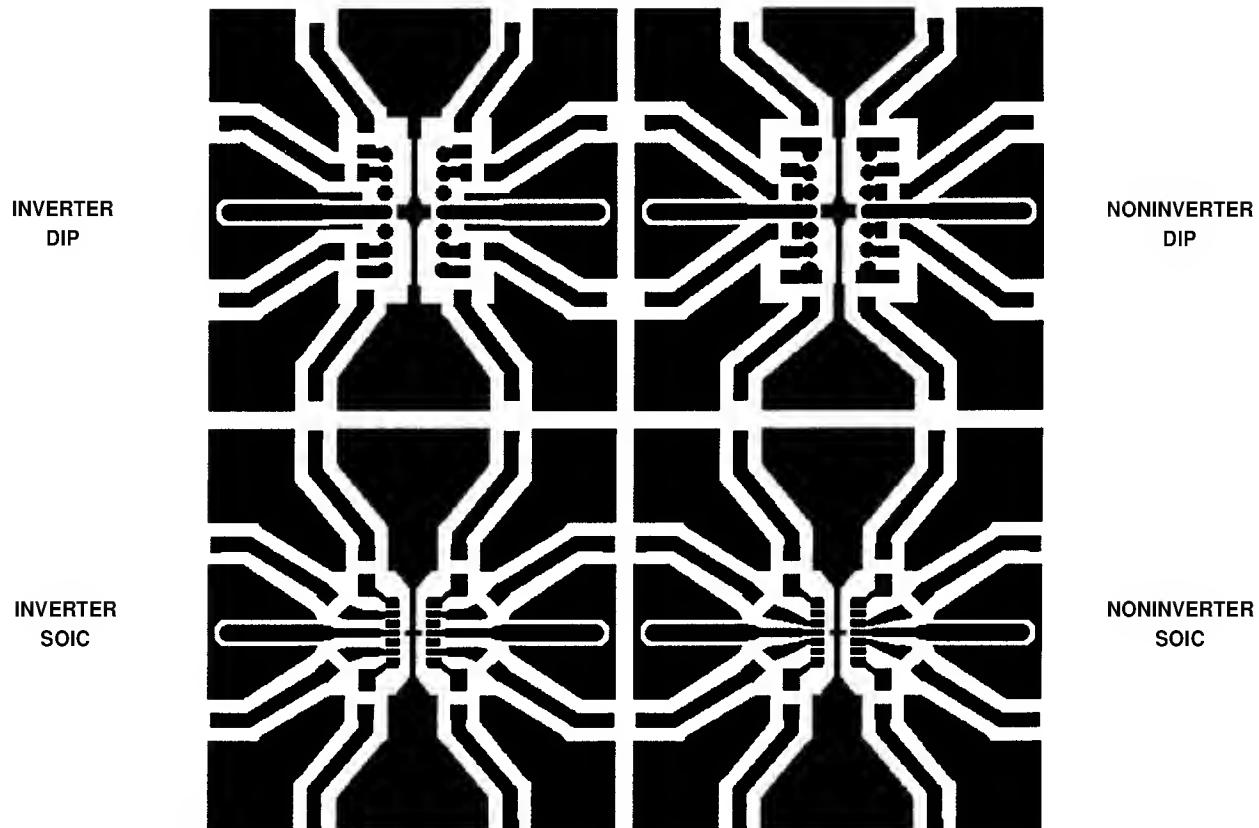


Figure 41. Evaluation Board Layout (Top Side)

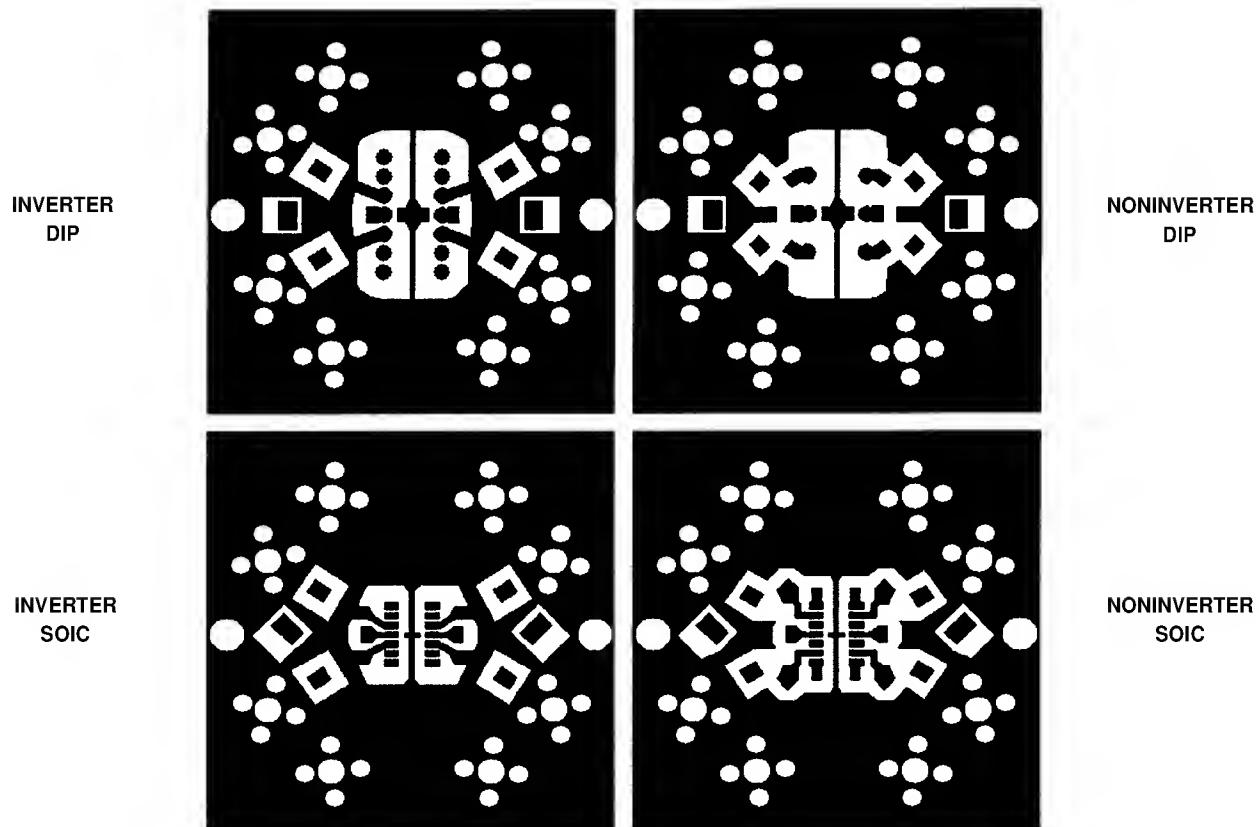
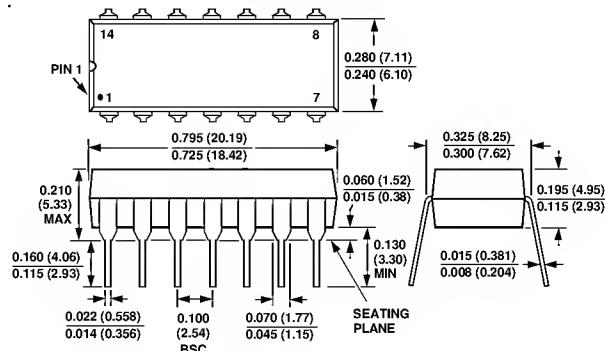
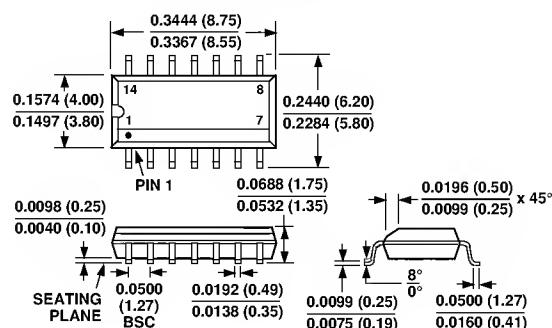


Figure 42. Evaluation Board Layout (Bottom Side, Looking Through the Board)

OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).

**14-Pin Plastic DIP
(N Package)****14-Pin Plastic SOIC
(R Package)**

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